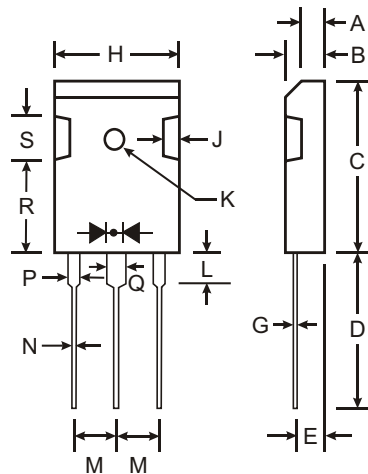


Features

- Schottky Barrier Chip
- Guard Ring Die Construction for Transient Protection
- Low Power Loss, High Efficiency
- High Surge Capability
- High Current Capability and Low Forward Voltage Drop
- For Use in Low Voltage, High Frequency Inverters, Free Wheeling, and Polarity Protection Applications

Mechanical Data

- Case: Molded Plastic
- Plastic Material: UL Flammability Classification Rating 94V-0
- Moisture sensitivity: Level 1 per J-STD-020A
- Terminals: Plated Leads Solderable per MIL-STD-202, Method 208
- Polarity: As Marked on Body
- Marking: Type Number
- Weight: 5.6 grams (approx.)



TO-3P		
Dim	Min	Max
A	1.88	2.08
B	4.68	5.36
C	20.63	22.38
D	18.5	21.5
E	2.1	2.4
G	0.51	0.76
H	15.38	16.25
J	1.90	2.70
K	2.90	3.65
L	3.78	4.50
M	5.2	5.7
N	0.89	1.53
P	1.82	2.46
Q	2.92	3.23
R	11.70	12.84
S	—	6.10
All Dimensions in mm		

Maximum Ratings and Electrical Characteristics @ T_A = 25°C unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load.
 For capacitive load, derate current by 20%.

Characteristic	Symbol	MBR 4030PT	MBR 4035PT	MBR 4040PT	MBR 4045PT	MBR 4050PT	MBR 4060PT	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	30	35	40	45	50	60	V
RMS Reverse Voltage	V _{R(RMS)}	21	24.5	28	31.5	35	42	V
Average Rectified Output Current @ T _C = 125°C (Note 1)	I _O	40						A
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	I _{FSM}	400						A
Forward Voltage Drop @ I _F = 20A, T _C = 25°C @ I _F = 20A, T _C = 125°C	V _{FM}	0.70 0.60				0.80 0.70		V
Peak Reverse Current @ T _C = 25°C at Rated DC Blocking Voltage @ T _C = 125°C	I _{RM}	1.0 100						mA
Typical Total Capacitance (Note 2)	C _T	1100						pF
Typical Thermal Resistance Junction to Case (Note 1)	R _{θJC}	1.4						°C/W
Voltage Rate of Change (Rated V _R)	dV/dt	10,000						V/μs
Operating and Storage Temperature Range	T _J , T _{STG}	-65 to +150						°C

- Notes: 1. Thermal resistance junction to case mounted on heatsink.
 2. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.

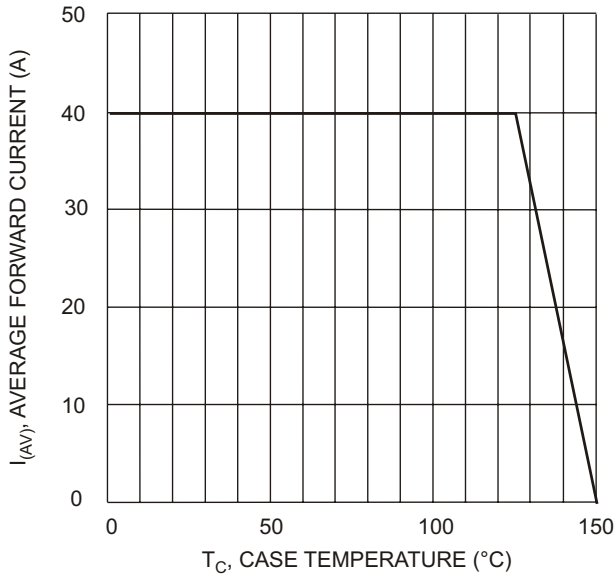


Fig. 1 Forward Current Derating Curve

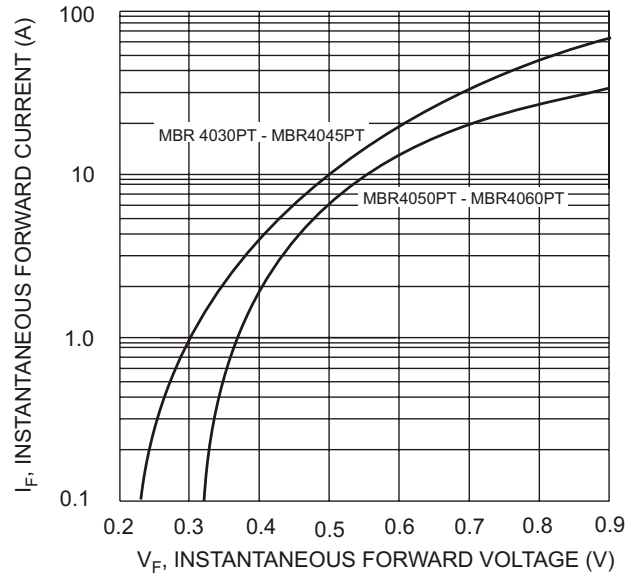


Fig. 2 Typical Forward Characteristics (per element)

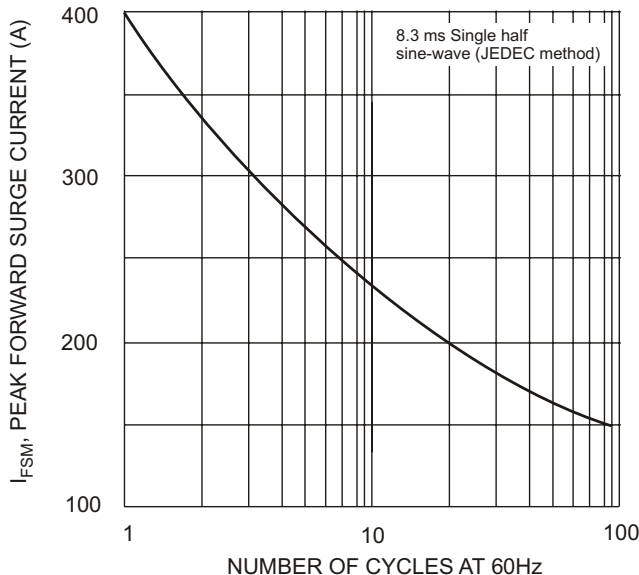


Fig. 3 Max Non-Repetitive Surge Current

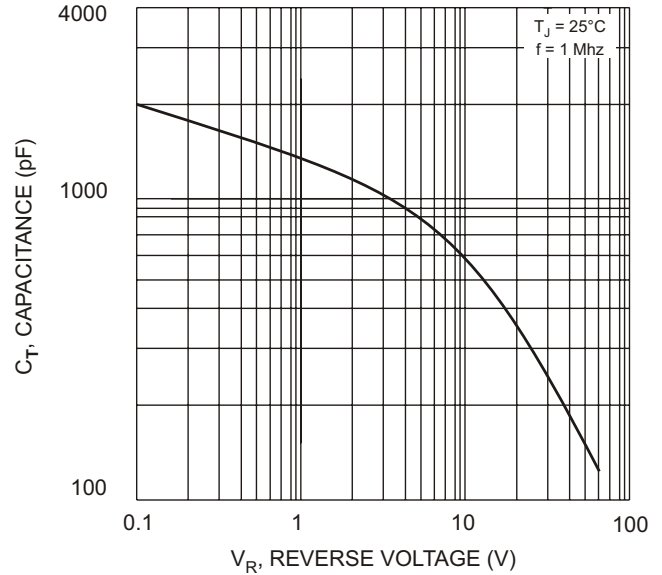


Fig. 4 Typical Total Capacitance

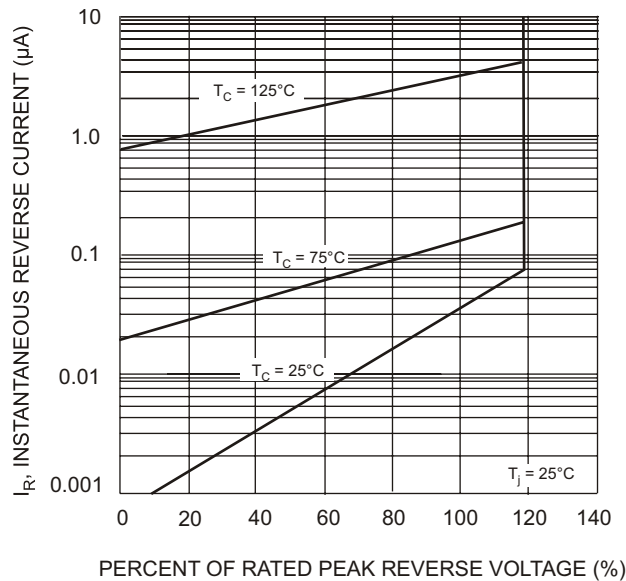


Fig. 5 Typical Reverse Characteristics